EGISMOS 940nm Laser Diode

Green Laser Diode

Application Industrial use / Biomedical Property Wavelength $\lambda = 940 \text{ nm}$

Output Power = 200 mW Package Type = ϕ 5.6 mm Introductiont

Egismos currently markets AlGaAs infrared laser diodes in the 780nm ~1550nm wavelengths range. The low operating current and high temperature of the laser diodes are achieved through using misoriented substrate and MQW (Strain compensated) active layer. Egismos laser diodes are highly rated in a broad range of applications including, but not limited to, laser pointers, green lasers, blue laser DVD, laser barcode scanners, diode laser equipments, medical instruments and aerospace applications.



Blue Laser Diode Key features

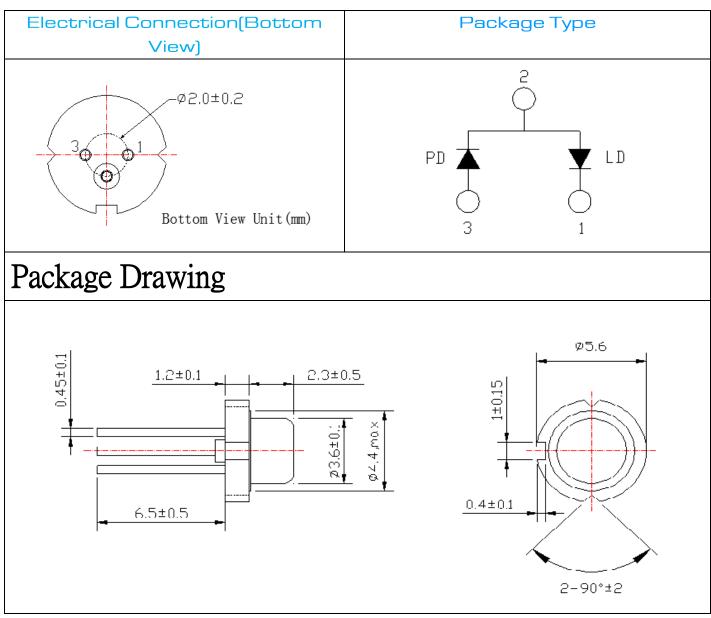
Absolute Maximum Rating at Tc=25°C						
Items	Symbols	Values	Unit			
Optical Output Power	Po(CW)	200	mW			
Reverse Voltage	V	2	V			
Operating Temperature	То	-10~+65	°C			
Storage Temperature	Ts	-40~+85	°C			

Electrical and Optical Characteristics at Tc=25 \degree						
Item	Symbols	Min	Тур.	Max.	Unit	Condition
Optical Output Power	Ро	-	-	200	mW	-
Threshold Current	lth	-	50	75	mA	-
Operating Current	Іор	-	375	420	mA	Po=200mW
Operating Voltage	Vop	-	2.2	2.7	V	Po=200mW
Peak Wavelength	λр	932	943	952	nm	Po=200mW



|--|

<u>EGISMOS</u>	940nm Laser Diode			D6-6-940-200		
Beam Divergence	θ//(*2)	24	30	36	deg	Po=200mW
(FWHM)	θ	24	30	36	deg	Po=200mW



Specifications are subject to change without notice.



